



Complementary Output Hall Effect Latch

■ Features

- On-chip Hall sensor with two different sensitivity and hysteresis settings for AH276
- 400mA (avg) output sink current
- Built-in protecting diode only for chip reverse power connecting
- -20°C to 85°C operating temperature
- Low profile 4 pin SIP package

Applications

- Dual-coil Brush-less DC Motor
- Dual-coil Brush-less DC Fan
- Revolution Counting
- Speed Measurement

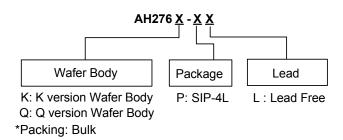
General Description

AH276 are integrated Hall sensors with output drivers, mainly designed for electronic commutation of brush-less DC Fan. This IC internally includes the regulator, protecting diode, Hall plate, amplifier, comparator, and a pair of complementary open-collector outputs (DO, DOB).

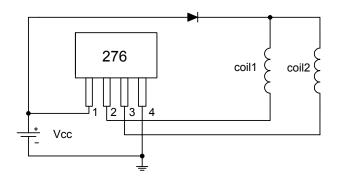
While the magnetic flux density (B) is larger than operate point (Bop), DO will turn on (low), and meanwhile DOB will turn off (high). Each output is latched until B is lower than release point (Brp), and then DO > DOB transfer each state.

For DC fan application, sometimes need to test power reverse connection condition. Internal diode only protects chip-side but not for coil-side. If necessary, add one external diode to block the reverse current from coil-side.

■ Ordering Information



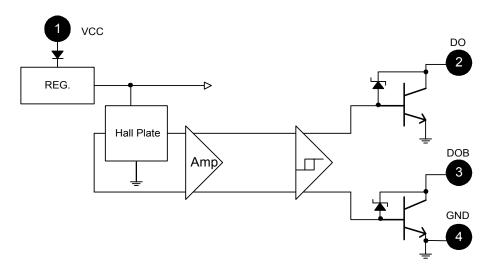
■ Typical Application Circuit



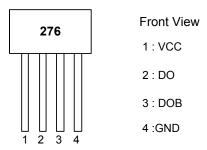
Brush-less DC Fan



■ Block Diagram



■ Pin Assignment



Name	P/I/O	Pin#	Description
Vcc	Р	1	Power Supply Input
DO	0	2	Output Pin
DOB	0	3	Output Pin
GND	Р	4	Ground



■ Absolute Maximum Ratings (at Ta=25°C)

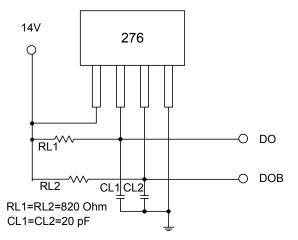
Characteristics		Symbol	Values	Unit		
Supply voltage		V _{CC}	20	V		
Reverse V _{CC} Polarity Voltage		V_{RCC}	-20	V		
Magnetic flux density		В	Unlimited			
	Continuous		0.4			
Output "on" current	Hold	lc	0.5	Α		
	Peak (Start Up)		0.7			
Operating temperature range		Та	-20~+85	°C		
Storage temperature range		Ts	-65~+150	°C		
Package Power Dissipation		PD	550	mW		
Maximum Junction Temp		Tj	150	°C		

■ Electrical Characteristics (T=+25°C)

Characteristic	Symbol	Conditions	Min	Тур	Max	Units	
Low Supply Voltage	Vce	Vcc=3.5V, I _L =100mA	-	0.4	-	V	
Supply Voltage	Vcc	K version	3.5	-	20	V	
Supply Voltage	VCC	Q version	2.5*	1	20	V	
Output Zener Breakdown	Vz	K version	ı	46	ı	V	
Output Zerier Breakdown	٧Z	Q version	-	35	-	V	
Output Saturation Voltage	Vce(sat)	Vcc=14V, I _L =300mA	-	0.7	0.8	V	
Output Leakage Current	Icex	Vce=14V, Vcc=14V	-	< 0.1	10	μΑ	
Supply Current	Icc	Vcc=20V, Output Open	-	16	25	mA	
Output Rise Time	tr	Vcc=14V, R _L =820Ω, C _L =20pF	-	3.0	10	μs	
Output Falling Time	tf	Vcc=14V, R_L =820 Ω , C_L =20pF	•	0.3	1.5	μs	
Switch Time Differential	Δt	Vcc=14V, R _L =820Ω, C _L =20pF	-	3.0	10	μs	

^{*}The output of DO/DOB will be switched on/off after supply voltage reaching the 2.5V.

■ Test Circuit





■ Magnetic Characteristics (Ta=+25°C, V_{cc}=12V)

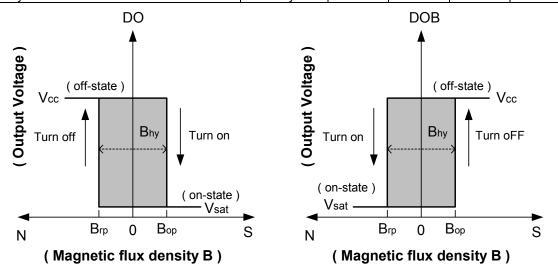
K version (1mT = 10 Gauss)

Characteristic Symbol Min. Typ. Max. Unit

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Operate Point	Вор	•	•	110	Gauss
Release Point	Brp	-110	•	-	Gauss
Hysteresis	Bhy	-	110	-	Gauss

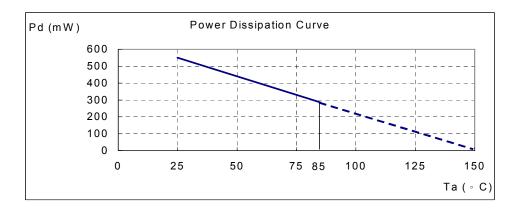
Q version

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Operate Point	Вор	5	-	70	Gauss
Release Point	Brp	-70	-	-5	Gauss
Hysteresis	Bhy	-		-	Gauss



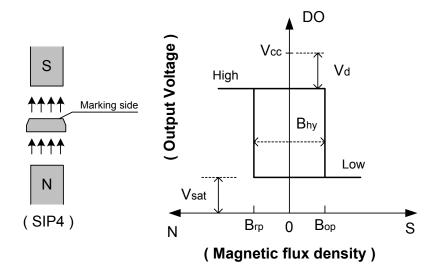
■ Performance Characteristics (SIP-4)

Ta (°C)	25	50	60	70	80	85	90	95	100
Pd (mW)	550	440	396	352	308	286	264	242	220
Ta (°C)	105	110	115	120	125	130	135	140	150
Pd (mW)	198	176	154	132	110	88	66	44	0

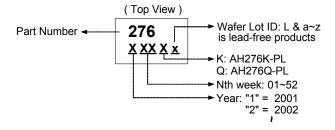




■ Operating Characteristics



■ Marking Information





■ Package Information

